

8-bit compatible shift / store register BU4094BC / BU4094BCF / BU4094BCFV

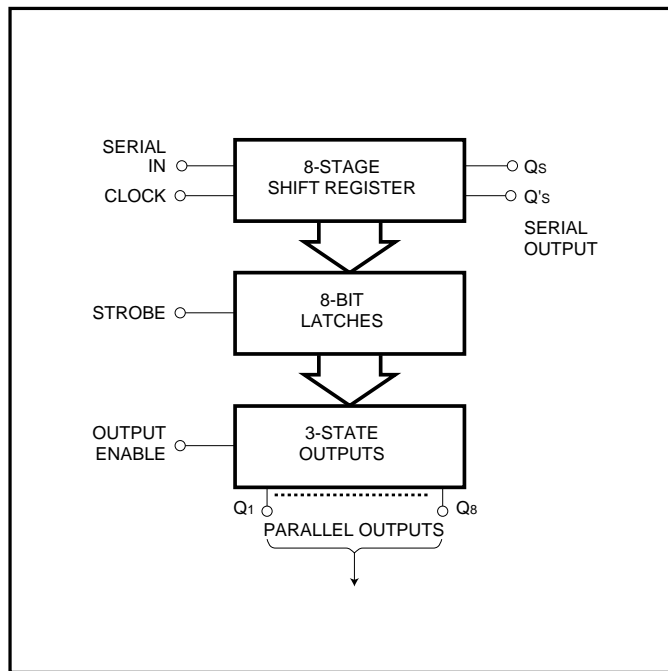
The BU4094BC, BU4094BCF, and BU4094BCFV are shift / store registers, each consisting of an 8-bit register and an 8-bit latch.

As the data in the shift register can be latched by an asynchronous strobe input, it is possible to hold the output in the data transfer mode.

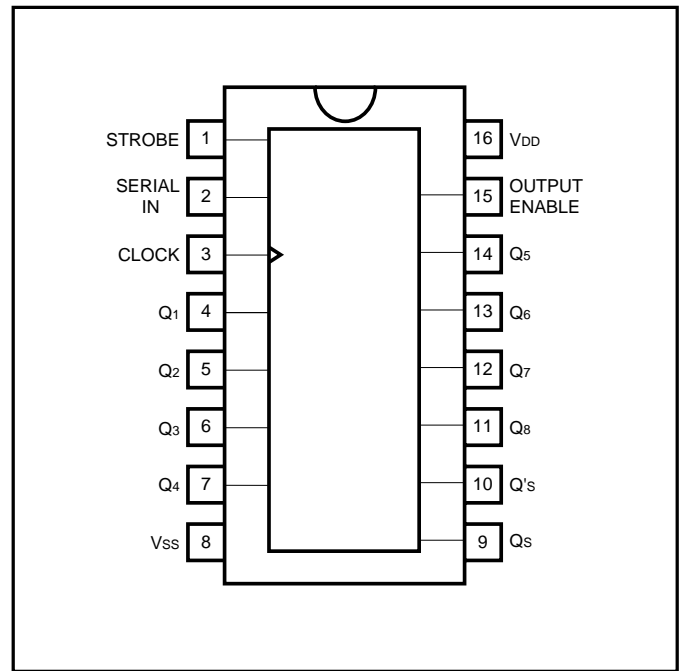
The tri-state parallel output can be connected directly with an 8-bit bus line.

These registers are suitable for in-line / parallel data conversion, data receivers and other similar applications.

●Logic circuit diagram



●Block diagram



●Truth table

CLOCK	OUTPUT ENABLE	STROBE	SERIAL IN	Parallel output		Serial output	
				Q ₁	Q _n	Q _s	Q' _s
↑	H	H	L	L	Q _{n-1}	Q ₇	NC
↑	H	H	H	H	Q _{n-1}	Q ₇	NC
↑	H	L	X	NC	NC	Q ₇	NC
↑	L	X	X	Z	Z	Q ₇	NC
↓	H	X	X	NC	NC	NC	Q _s
↓	L	X	X	Z	Z	NC	Q _s

NC: No Change Z: High Impedance X: Irrelevant

● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Power supply voltage	V _{DD}	- 0.5 ~ + 20	V
Power dissipation	P _d	1000 (DIP), 500 (SOP) 400 (SSOP)	mW
Operating temperature	Topr	- 40 ~ + 85	°C
Storage temperature	Tstg	- 55 ~ + 150	°C
Input voltage	V _{IN}	- 0.5 ~ V _{DD} + 0.5	V

● Electrical characteristics

DC characteristics (unless otherwise noted, V_{SS} = 0V, Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	V _{DD} (V)	Conditions
Input high level voltage	V _{IH}	3.5	—	—	V	5	—
		7.0	—	—		10	
		11.0	—	—		15	
Input low level voltage	V _{IL}	—	—	1.5	V	5	—
		—	—	3.0		10	
		—	—	4.0		15	
Input high level current	I _{IH}	—	—	0.3	μA	15	V _{IH} = 15V
Input low level current	I _{IL}	—	—	- 0.3	μA	15	V _{IL} = 0V
Output high level voltage	V _{OH}	4.95	—	—	V	5	I _o = 0mA
		9.95	—	—		10	
		14.95	—	—		15	
Output low level voltage	V _{OL}	—	—	0.05	V	5	I _o = 0mA
		—	—	0.05		10	
		—	—	0.05		15	
Output high level current	I _{OH}	- 0.44	—	—	mA	5	V _{OH} = 4.6V
		- 1.1	—	—		10	V _{OH} = 9.5V
		- 3.0	—	—		15	V _{OH} = 13.5V
Output low level current	I _{OL}	0.44	—	—	mA	5	V _{OL} = 0.4V
		1.1	—	—		10	V _{OL} = 0.5V
		3.0	—	—		15	V _{OL} = 1.5V
Output high level disable current	I _{DH}	—	—	1.0	μA	15	V _{OUT} = 15V
Output low level disable current	I _{DL}	—	—	- 1.0	μA	15	V _{OUT} = 0V
Static current dissipation	I _{DD}	—	—	20	μA	5	V _I = V _{DD} , or GND
		—	—	40		10	
		—	—	80		15	

Switching characteristics (unless otherwise noted, $V_{SS} = 0V$, $T_a = 25^\circ C$, $C_L = 50pF$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	V_{DD} (V)	Conditions	Measurement circuit
Output rise time	t_{TLH}	—	100	—	ns	5	—	Fig.1
		—	50	—	ns	10		
		—	40	—	ns	15		
Output fall time	t_{THL}	—	100	—	ns	5	—	Fig.1
		—	50	—	ns	10		
		—	40	—	ns	15		
Propagation delay time, CLOCK to Qs	t_{PLH} t_{PHL}	—	350	600	ns	5	—	Fig.1
		—	125	250	ns	10		
		—	95	190	ns	15		
Propagation delay time, CLOCK to Qs	t_{PLH} t_{PHL}	—	230	460	ns	5	—	Fig.1
		—	110	220	ns	10		
		—	75	150	ns	15		
Propagation delay time, CLOCK to Qn	t_{PLH} t_{PHL}	—	420	840	ns	5	—	Fig.1
		—	195	390	ns	10		
		—	135	270	ns	15		
Propagation delay time, STROBE to Qn	t_{PLH} t_{PHL}	—	290	580	ns	5	—	Fig.1
		—	145	290	ns	10		
		—	100	200	ns	15		
3-state propagation delay time, Output Enable to Qn	t_{PHZ} t_{PZH}	—	140	280	ns	5	$R_L = 1k\Omega$	Fig.2
		—	75	150	ns	10		
		—	55	110	ns	15		
3-state propagation delay time, Output Enable to Qn	t_{PLZ} t_{PZL}	—	140	280	ns	5	$R_L = 1k\Omega$	Fig.2
		—	75	150	ns	10		
		—	55	110	ns	15		
Minimum setup time, DATA to CLOCK	t_{SU}	—	20	125	ns	5	—	Fig.1
		—	8	55	ns	10		
		—	6	35	ns	15		
Minimum hold time, CLOCK to DATA	t_H	—	10	40	ns	5	—	Fig.1
		—	10	20	ns	10		
		—	5	15	ns	15		
Minimum clock pulse width	t_W	—	100	200	ns	5	—	Fig.1
		—	50	100	ns	10		
		—	40	80	ns	15		
Maximum clock rise time and fall time	$t_r^{(CL)}$ $t_f^{(CL)}$	NO Limit			μs	5	—	Fig.1
					μs	10		
					μs	15		
Maximum clock frequency	f_{CL}	1.25	5	—	MHz	5	—	Fig.1
		2.5	10	—	MHz	10		
		3.0	12.5	—	MHz	15		
Minimum strobe pulse width	t_{WH}	—	100	200	ns	5	—	Fig.1
		—	40	80	ns	10		
		—	35	70	ns	15		
Input capacitance	C_{IN}	—	5	—	pF	—	—	—

● Measurement circuits

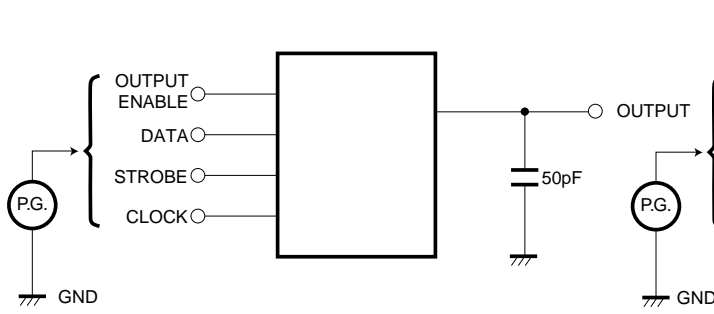


Fig. 1 Switching waveform

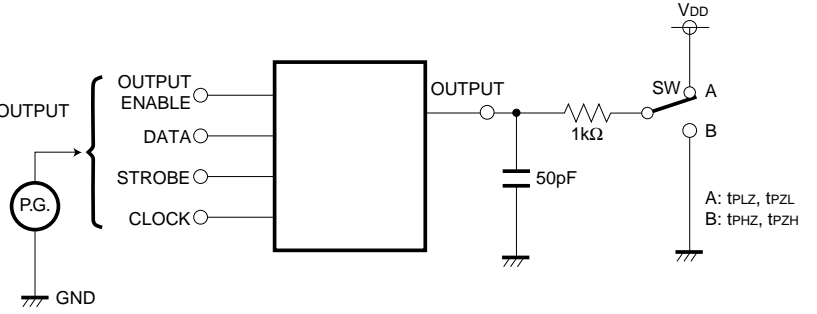


Fig. 2 3-state delay time

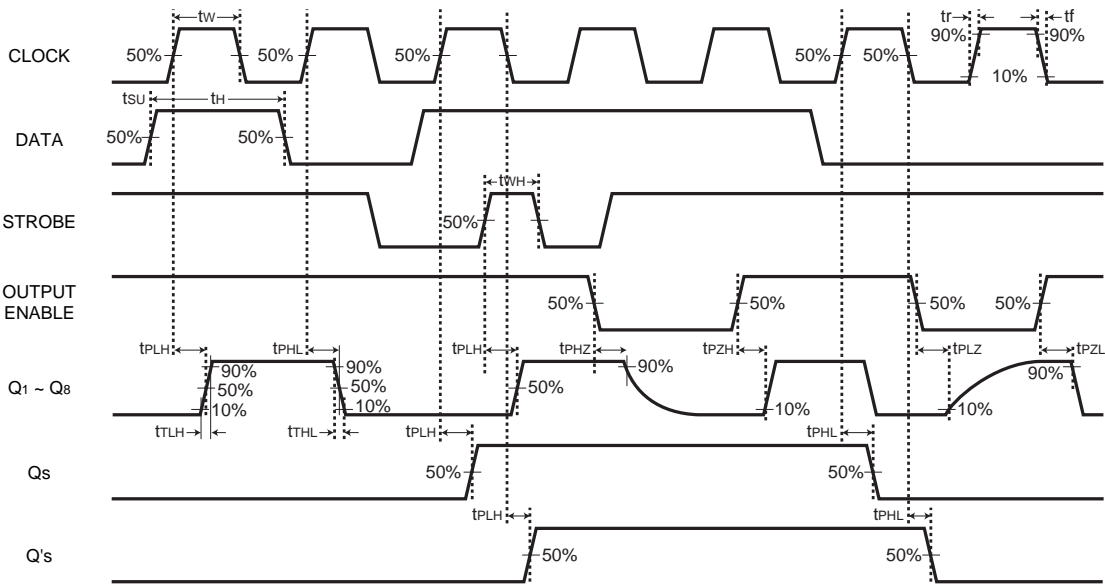


Fig. 3 Switching time test waveform

● Electrical characteristic curve

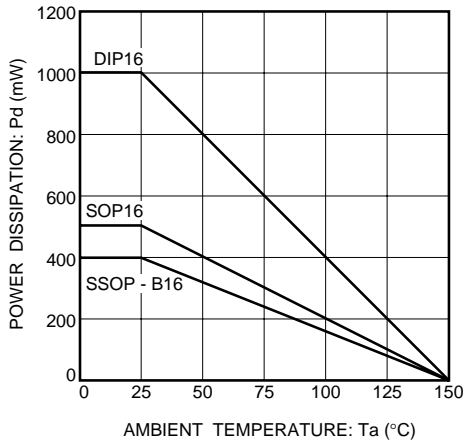


Fig. 4 Power dissipation vs. ambient temperature

●External dimensions (Units: mm)

